

SF501 THRU SF509

SUPER FAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 1000 Volts

Forward Current - 5.0 Amperes

Features

- Superfast recovery times
- Low forward voltage, high current capability
- Hermetically sealed
- Low leakage
- High surge capability
- Plastic package has Underwriters Laboratories Flammability classification 94V-0 utilizing Flame retardant epoxy molding compound



DO-201AD

Mechanical Data

- Case: Molded plastic, DO-201AD
- Terminals: Axial leads, solderable to MIL-STD-202, method 208
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.042 ounce, 1.19 grams

DIMENSIONS										
DIM	inches		m	Note						
	Min.	Max.	Min.	Max.	Note					
А	0.283	0.374	7.20	9.50						
В	0.189	0.208	4.80	5.30	ф					
С	0.048	0.051	1.20	1.30	ф					
D	1.000	-	25.40	-						

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	SF 501	SF 502	SF 503	SF 504	SF 505	SF 506	SF 507	SF 508	SF 509	Units
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	600	800	1000	Volts
Maximum average forward current 0.375" (9.5mm) lead length at $\rm T_{A}{=}55^\circ\!C$	imum average forward current '5" (9.5mm) lead length at $T_{\rm A}$ =55 °C II.							Amps			
Peak forward surge current, I(surge): 8.3mS single half sine-wave stperimposed on rated load (MIL-STD-750D 4066 method)	I _{fsm}	150.0								Amps	
Maximum forward voltage at 5.0A DC	V _F	0.95 1.25 1.40						Volts			
$\begin{array}{llllllllllllllllllllllllllllllllllll$	I _R	5.0 500.0								μA	
Maximum reverse recovery time (Note 1)	T _{rr}	35.0									nS
Typical junction capacitance (Note 2)	C	100.0								ρF	
Typical thermal resistance (Note 3)	R _{⊎JA}	25.0								°C/W	
Operating and storage temperature range	T _J , T _{stg}	-55 to +150							°C		

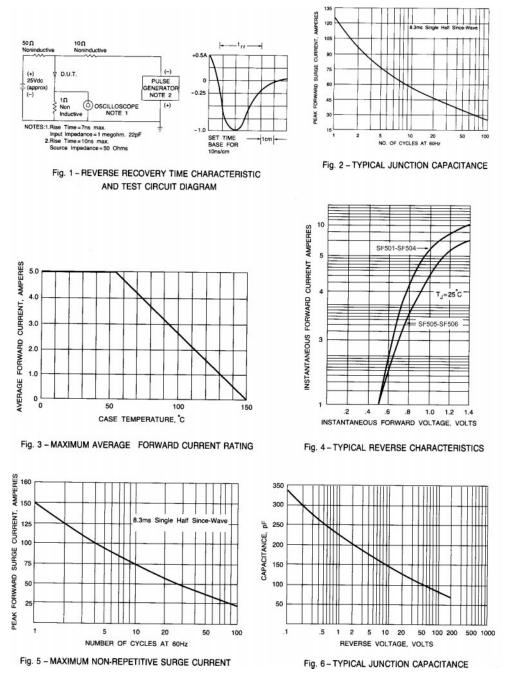
Notes:

(1) Reverse recovery test conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{rr}=0.25A$

(2) Measured at 1.0MHz and applied reverse voltage of 4.0 VDC

(3) Thermal resistance from junction to ambient and from junction to lead length 0.375" (9.5mm) P.C.B. mounted

RATINGS AND CHARACTERISTIC CURVES



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